KPTR-3216CGCK

3.2 x 1.6 mm SMD Chip LED Lamp



DESCRIPTIONS

- The Green source color devices are made with AlGaInP on GaAs substrate Light Emitting Diode
- · Electrostatic discharge and power surge could damage the LEDs
- · It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs
- · All devices, equipments and machineries must be electrically grounded

FEATURES

- 3.2 mm x 1.6 mm SMD LED, 1.05 mm thickness
- Low power consumption
- Wide viewing angle
- · Ideal for backlight and indicator
- Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- · Halogen-free
- RoHS compliant

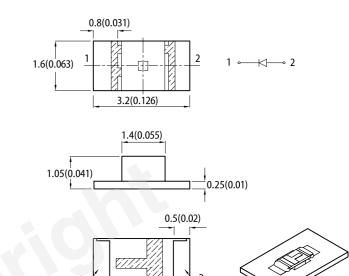
APPLICATIONS

- Backlight
- · Status indicator
- · Home and smart appliances
- Wearable and portable devices
- · Healthcare applications

ATTENTION

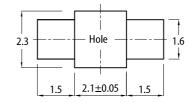
Observe precautions for handling electrostatic discharge sensitive devices

PACKAGE DIMENSIONS



RECOMMENDED SOLDERING PATTERN

(units : mm; tolerance : \pm 0.1)



Notes

All dimensions are in millimeters (inches).
 Tolerance is ±0.2(0.008") unless otherwise noted.

3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.

The device has a single mounting surface. The device must be mounted according to the specifications.

SELECTION GUIDE

Part Number	mber Emitting Color (Material)	Lens Type	lv (mcd) @ 20mA ^[2]		Viewing Angle ^[1]	
r art Number			Min.	Тур.	201/2	
KPTR-3216CGCK	Green (AlGalnP)	Water Clear	20	50	140°	

Notes

1. 61/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
 2. Luminous intensity / luminous flux: +/-15%.
 3. Luminous intensity value is traceable to CIE127-2007 standards.

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ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Parameter	Currents al	Emitting Color	Value		11
Farameter	Symbol	Emitting Color	Тур.	Max.	Unit
Wavelength at Peak Emission I_F = 20mA	λ_{peak}	Green	574	-	nm
Dominant Wavelength I_F = 20mA	λ_{dom} ^[1]	Green	570	-	nm
Spectral Bandwidth at 50% Φ REL MAX I _F = 20mA	Δλ	Green	20	-	nm
Capacitance	С	Green	15	-	pF
Forward Voltage I _F = 20mA	V _F ^[2]	Green	2.1	2.5	V
Reverse Current ($V_R = 5V$)	I _R	Green	-	10	μΑ
Temperature Coefficient of λ_{peak} I_{F} = 20mA, -10°C \leq T \leq 85°C	$TC_{\lambda peak}$	Green	0.12	-	nm/°C
Temperature Coefficient of λ_{dom} I_{F} = 20mA, -10°C \leq T \leq 85°C	TC _{λdom}	Green	0.08	-	nm/°C
Temperature Coefficient of V_F I _F = 20mA, -10°C \leq T \leq 85°C	TCv	Green	-1.9	-	mV/°C

Notes: 1. The dominant wavelength (λd) above is the setup value of the sorting machine. (Tolerance λd : ±1nm.) 2. Forward voltage: ±0.1V. 3. Wavelength value is traceable to CIE127-2007 standards. 4. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

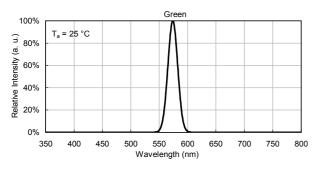
ABSOLUTE MAXIMUM RATINGS at T_A=25°C

Parameter	Symbol	Value	Unit
Power Dissipation	P _D	75	mW
Reverse Voltage	V _R	5	V
Junction Temperature	Tj	115	°C
Operating Temperature	T _{op}	-40 to +85	°C
Storage Temperature	T _{stg}	-40 to +85	°C
DC Forward Current	IF	30	mA
Peak Forward Current	I _{FM} ^[1]	150	mA
Electrostatic Discharge Threshold (HBM)	-	3000	V
Thermal Resistance (Junction / Ambient)	$R_{th\ JA}^{\ [2]}$	740	°C/W
Thermal Resistance (Junction / Solder point)	R _{th JS} ^[2]	600	°C/W

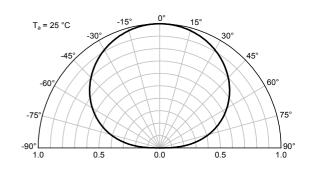
Notes: 1. 1/10 Duty Cycle, 0.1ms Pulse Width. 2. R_{In. J.A}. R_{In. J.S} Results from mounting on PC board FR4 (pad size ≥ 16 mm² per pad). 3. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

TECHNICAL DATA

RELATIVE INTENSITY vs. WAVELENGTH



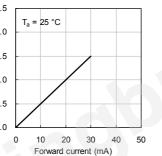
SPATIAL DISTRIBUTION



Forward Current vs. Forward Voltage 50 2.5 Luminous intensity normalised at 20 mA T_a = 25 °C 40 2.0 Forward current (mA) 30 1.5 20 1.0 10 0.5 0 0.0 1.9 2.1 2.3 1.5 1.7 2.5 Forward voltage (V)

Luminous Intensity vs. **Forward Current**

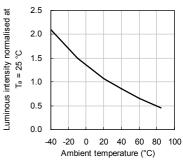
GREEN



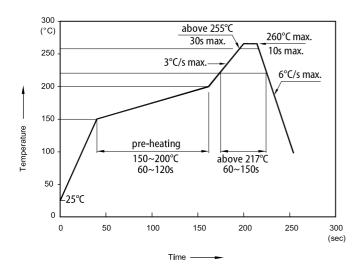
50 (mA) forward current 40 30 20 Permissible 10 0 -40 -20 0 20 40 60 80 100 Ambient temperature (°C)

Forward Current Derating Curve

Luminous Intensity vs. Ambient Temperature



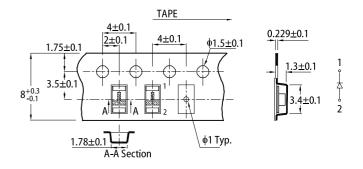
REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS



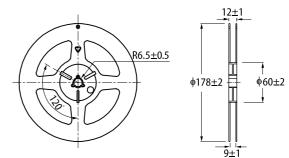
Notes

- Notes: 1. Don't cause stress to the LEDs while it is exposed to high temperature. 2. The maximum number of reflow soldering passes is 2 times. 3. Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

TAPE SPECIFICATIONS (units : mm)

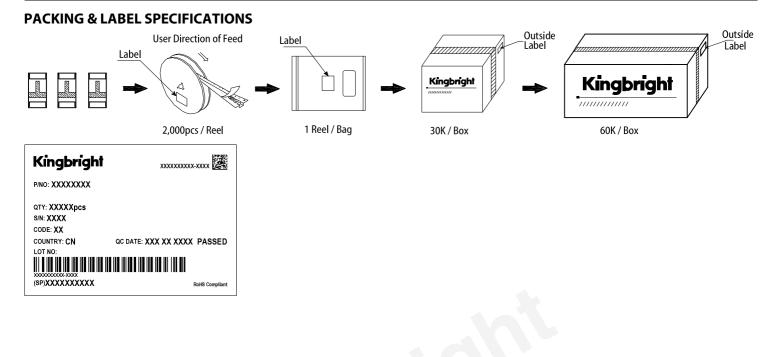


REEL DIMENSION (units : mm)



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PRECAUTIONARY NOTES

- The information included in this document reflects representative usage scenarios and is intended for technical reference only.
- The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications. 2.
- the latest datasheet for the updated specifications.
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